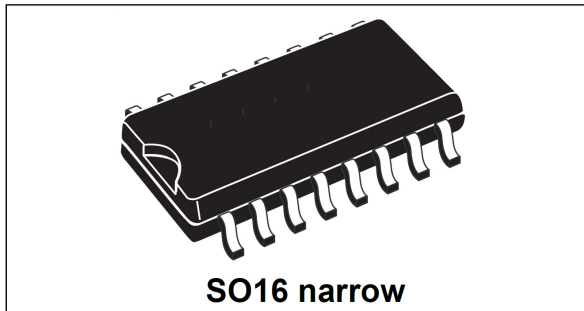


1050 V High voltage converter

Data brief



Features

- 1050 V avalanche rugged power section
- Current mode PWM controller
- Embedded high voltage startup and sense FET
- Drain current limitation (OCP)
- Standby power < 30 mW at 230 VAC
- Jittered switching frequency (60 kHz \pm 4 kHz) for low EMI
- Embedded error amplifier for non-isolated SMPS
- On-board soft-start
- Safe auto-restart after a fault condition
- Hysteretic thermal shutdown

Applications

- SMPS for energy metering
- Auxiliary power supplies for 3-phase input industrial systems
- LED driver

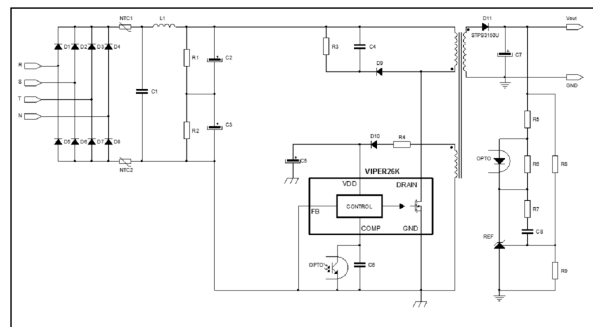
SMPS topologies

Isolated flyback (secondary-side and primary-side regulation), non-isolated flyback, buck, buck-boost.

Description

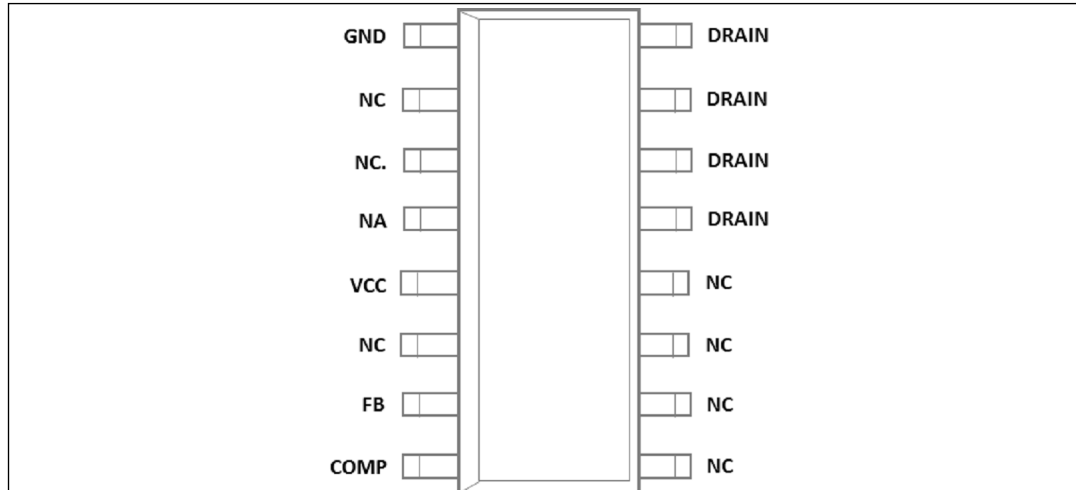
The device is an offline converter with a 1050 V avalanche rugged power section, a PWM controller, user defined overcurrent limit, protection against feedback network disconnection, hysteretic thermal protection, soft start-up and safe auto-restart after any fault condition.

Advance frequency jittering reduces EMI filter cost. Burst mode operation and the device's very low consumption both help to meet the standard set by energy saving regulations.



1 Pin description

Figure 1. Connection diagram



Note: A PCB copper area has to be provided under DRAIN pins to heat dissipation.

Table 1. Pin description

| SO16N | Name | Function |
|---------|-------|--|
| 1 | GND | Ground. Connected to the source of the internal power MOSFET and controller ground reference. |
| 2, 3 | N.C. | Not internally connected. It is highly recommended to connect it to GND (pin 1) or leave floating. |
| 4 | N.A. | Not available for user. This pin is mechanically connected to the controller die pad of the frame. In order to improve the noise immunity, it is highly recommended to connect it to GND (pin 1). |
| 5 | VCC | Supply voltage of the control section. This pin provides the charging current of the external capacitor. |
| 6 | N.C. | Not available for user. It is highly recommended to connect it to GND (pin 1). |
| 7 | FB | Inverting input of the internal trans-conductance error amplifier. Connecting the converter output to this pin through a single resistor results in an output voltage equal to the error amplifier reference voltage. An external resistors divider is required for higher output voltages. |
| 8 | COMP | Output of the internal trans conductance error amplifier. The compensation network has to be placed between this pin and GND to achieve stability and good dynamic performance of the voltage control loop. The pin is used also to directly control the PWM with an optocoupler. The linear voltage range extends from V_{COMPL} to V_{COMP} . |
| 9 - 12 | N.C. | Not internally connected. It can be connected to GND or left floating. |
| 13 - 16 | DRAIN | High voltage drain pin. The built-in high voltage switched start-up bias current is drawn from this pin too. Pins connected to the metal frame to facilitate heat dissipation. |

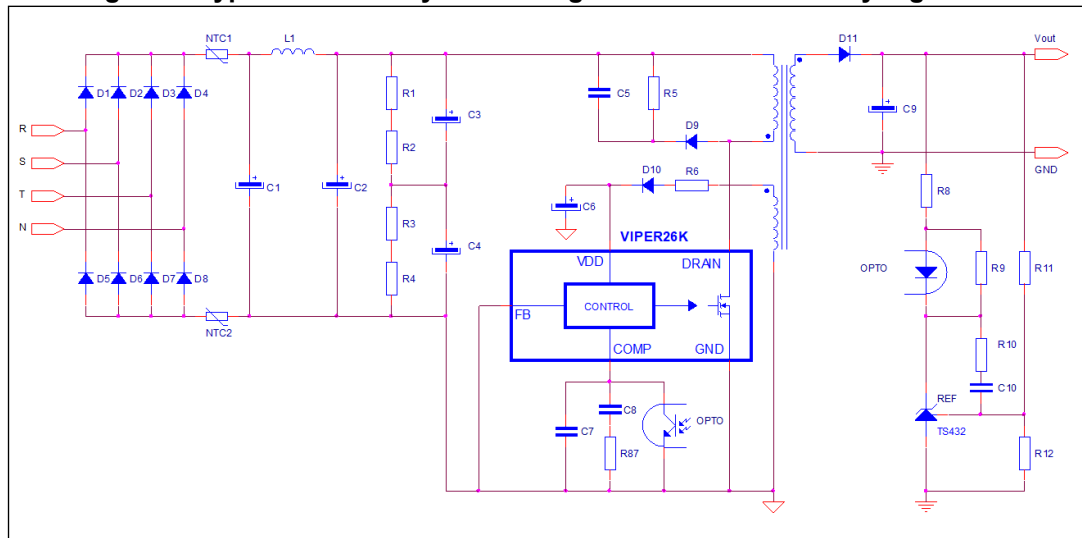
2 Electrical characteristics

Table 2. Electrical and thermal characteristics

| Symbol | Parameter | Value |
|---------------|--|--|
| $V_{(BR)DSS}$ | Breakdown voltage | 1050 V |
| $R_{DS(on)}$ | Drain-source ON state resistance (max.@25C) | 8.5 Ω |
| V_{START} | Drain-source start voltage | 60 V (max.) |
| V_{DD} | Operating voltage range | [11.5 - 23.5] V |
| V_{REF_FB} | E/A input voltage | 3.3 V (typ.) |
| I_{DLIM} | Drain current limitation | 500mA (VIPer265K) 700mA (VIPer267K) |
| F_{OSC} | Switching frequency | 60 KHz (typ.) |
| T_{SD} | Thermal shutdown temperature | 160 °C (typ.) |
| R_{thJA} | Thermal resistance junction ambient ⁽¹⁾ (Dissipated power = 1 W) | 80 °C/W |

1. When mounted on a standard single side FR4 board with 100 mm² (0.155 sq in) of Cu (35 μ m thick).

Figure 2. Typical isolated flyback configuration with secondary regulation



3 Ordering information

Table 3. Order codes

| Order Code | I _{DLIM} | Package | Packaging |
|--------------|-------------------|---------|-------------|
| VIPER265KDTR | 500 mA | SO16N | Tape & Reel |
| VIPER267KDTR | 700 mA | | |

4 Revision history

Table 4. Document revision history

| Date | Revision | Changes |
|-------------|----------|-----------------|
| 08-Jan-2019 | 1 | Initial release |

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